# One Watt High Current PNP Transistor

#### **Features**

• This is a Pb-Free Device\*

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector - Emitter Voltage	V <sub>CE</sub>	50	Vdc
Collector - Base Voltage	V <sub>CB</sub>	50	Vdc
Emitter – Base Voltage	V <sub>EB</sub>	5.0	Vdc
Collector Current - Continuous	I <sub>C</sub>	2.0	Adc
Total Power Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	900 5.0	mW mW/°C
Total Power Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	125	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	°C/W

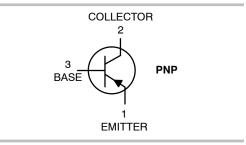
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

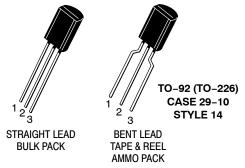


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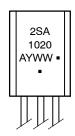
http://onsemi.com

## VOLTAGE AND CURRENT ARE NEGATIVE FOR PNP TRANSISTORS





#### **MARKING DIAGRAM**



A = Assembly Location

Y = Year
WW = Work Week
Pb-Free Package

(Note: Microdot may be in either location)

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### 2SA1020

### **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS	1		I	
Collector – Emitter Breakdown Voltage (Note 1) $(I_C = 10 \text{ mAdc}, I_B = 0)$	V <sub>(BR)</sub> CEO	50	-	Vdc
Collector Cutoff Current (V <sub>CB</sub> = 50 Vdc, I <sub>E</sub> = 0)	I <sub>CBO</sub>	_	1.0	μAdc
Emitter Cutoff Current $(V_{EB} = 5.0 \text{ V}, I_{C} = 0)$	I <sub>EBO</sub>	_	1.0	μAdc
ON CHARACTERISTICS (Note 2)	•			
DC Current Gain $(I_C = 500 \text{ mA}, V_{CE} = 2.0 \text{ V})$ $(I_C = 1.5 \text{ A}, V_{CE} = 2.0 \text{ V})$	h <sub>FE</sub>	70 40	240 -	-
Collector – Emitter Saturation Voltage ( $I_C = 1.0 \text{ A}, I_B = 50 \text{ mA}$ )	V <sub>CE(sat)</sub>	_	0.5	Vdc
Base – Emitter Saturation Voltage (I <sub>C</sub> = 1.0 A, I <sub>B</sub> = 50 mA)	V <sub>BE(sat)</sub>	-	1.2	Vdc
SMALL-SIGNAL CHARACTERISTICS	<u>.</u>			•
Current – Gain – Bandwidth Product (Note 3) (I <sub>C</sub> = 500 mAdc, V <sub>CE</sub> = 2.0 Vdc, f = 100 MHz)	f <sub>T</sub>	100	_	MHz

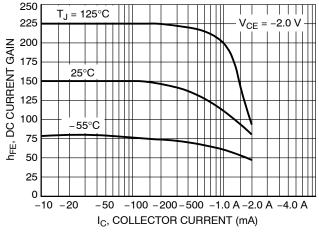
#### **ORDERING INFORMATION**

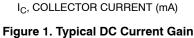
Device	Package	Shipping <sup>†</sup>
2SA1020RLRAG	TO-92 (Pb-Free)	2000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle = 2.0%.
 Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle = 2.0%.
 f<sub>T</sub> is defined as the frequency at which |h<sub>fe</sub>| extrapolates to unity.

### 2SA1020





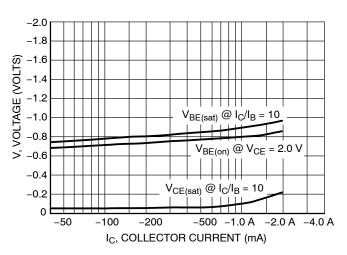


Figure 2. On Voltages

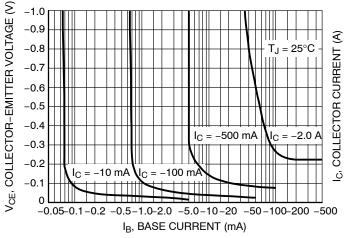


Figure 3. Collector Saturation Region

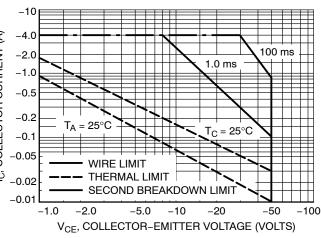
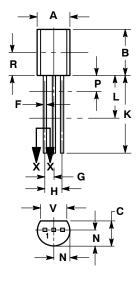


Figure 4. Safe Operating Area

#### 2SA1020

#### PACKAGE DIMENSIONS

#### TO-92 (TO-226) 1 WATT CASE 29-10 **ISSUE O**



STRAIGHT LEAD **BULK PACK** 



- DIMENSIONING AND TOLERANCING PER ANSI

  - Y14.5M, 1994. CONTROLLING DIMENSION: INCHES.
- CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED. DIMENSION FAPPLIES BETWEEN DIMENSIONS PAND L. DIMENSIONS AND J. APPLY BETWEEN DIMENSIONS DAMD J. APPLY BETWEEN DIMENSIONS LAND K. MINIMUM. THE LEAD DIMENSIONS ARE UNCONTROLLED IN DIMENSION P AND BEYOND DIMENSION K MINIMUM.

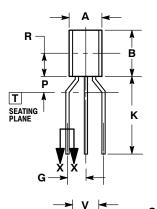
	INCHES		MILLIM	ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.44	5.21
В	0.290	0.310	7.37	7.87
С	0.125	0.165	3.18	4.19
D	0.018	0.021	0.46	0.53
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.018	0.024	0.46	0.61
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.135		3.43	
٧	0.135		3.43	

STYLE 14:

PIN 1. EMITTER

COLLECTOR

BASE



BENT LEAD TAPE & REEL AMMO PACK



#### NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: INCHES.
  CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- DIMENSION F APPLIES BETWEEN DIMENSIONS P DIMENSION A FIFLES BET WEEN DIMENSIONS F AND L DIMENSIONS D AND J APPLY BETWEEN DIMENSIONS L AND K MINIMUM. THE LEAD DIMENSIONS ARE UNCONTROLLED IN DIMENSION P AND BEYOND DIMENSION K MINIMUM.

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Α	0.175	0.205	4.44	5.21
В	0.290	0.310	7.37	7.87
С	0.125	0.165	3.18	4.19
D	0.018	0.021	0.46	0.53
G	0.094	0.102	2.40	2.80
J	0.018	0.024	0.46	0.61
K	0.500		12.70	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.135		3.43	
v	0.135		3 43	

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